

### **General Description**

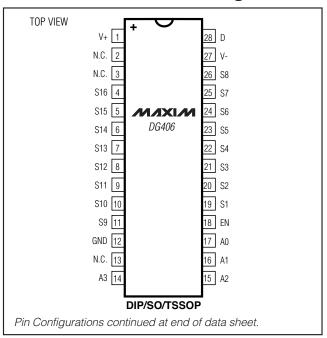
Maxim's redesigned DG406 and DG407 CMOS analog multiplexers now feature guaranteed matching between channels (8 $\Omega$ , max) and flatness over the specified signal range ( $9\Omega$ , max). These low on-resistance muxes (100 $\Omega$ , max) conduct equally well in either direction and feature guaranteed low charge injection (15pC, max). In addition, these new muxes offer low input off-leakage current over temperature—less than 5nA at +85°C.

The DG406 is a 1 of 16 multiplexer/demultiplexer and the DG407 is a dual 8-channel multiplexer/demultiplexer. Both muxes operate with a +5V to +30V single supply and with  $\pm 4.5 \text{V}$  to  $\pm 20 \text{V}$  dual supplies. ESD protection is guaranteed to be greater than 2000V per Method 3015.7 of MIL-STD 883. These improved muxes are pin-compatible plug-in upgrades for the industry standard DG406 and DG407.

### **Applications**

Sample-and-Hold Circuits Test Equipment Guidance and Control Systems Communications Systems **Data-Acquisition Systems** Audio Signal Routing

# Pin Configurations



#### **Features**

- Pin-Compatible Plug-In Upgrade for Industry Standard DG406/DG407
- ♦ Guaranteed Matching Between Channels, 8Ω (max)
- ♦ Guaranteed On-Resistance Flatness,  $9\Omega$  (max)
- ♦ Guaranteed Low Charge Injection, 15pC (max)
- ♦ Low On-Resistance 100Ω (max)
- ♦ Input Leakage, 5nA (max) at +85°C
- **♦** Low Power Consumption, 1.25mW (max)
- ♦ Rail-to-Rail Signal Handling
- **♦** Digital Input Controls TTL/CMOS Compatible
- ♦ ESD Protection >2000V per Method 3015.7

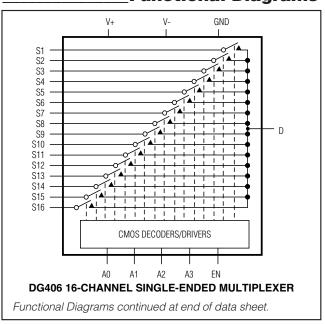
### Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
DG406CJ+	0°C to +70°C	28 Plastic DIP
DG406CWI+	0°C to +70°C	28 Wide SO
DG406C/D	0°C to +70°C	Dice*
DG406DJ+	-40°C to +85°C	28 Plastic DIP
DG406EWI+	-40°C to +85°C	28 Wide SO
DG406DN+	-40°C to +85°C	28 PLCC
DG406AK+	-55°C to +125°C	28 CERDIP
DG406EUI+	-40°C to +85°C	28 TSSOP

#### Ordering Information continued at end of data sheet.

- \*Contact factory for dice specifications.
- +Denotes a lead(Pb)-free/RoHS-compliant package.

# Functional Diagrams



MIXIM

Maxim Integrated Products 1

#### **ABSOLUTE MAXIMUM RATINGS**

(Voltage Referenced to V-) V+	28-Pin CERDIP (derate 16.67mW/°C above +70°C)1333mW 28-Pin TSSOP (derate 12.8mW/°C above +70°C)1025mW
GND0.3V, 25V Digital Inputs, S, D (Note 1)(V 2V) to (V+ + 2V) or	Operating Temperature Ranges DG406/DG407C0°C to +70°C
30mA (whichever occurs first) Continuous Current (any terminal)30mA	DG406/DG407D40°C to +85°C DG406/DG407AK55°C to +125°C
Peak Current, S or D	Storage Temperature Range65°C to +150°C
(pulsed at 1ms, 10% duty cycle max)100mA Continuous Power Dissipation (T <sub>A</sub> = +70°C)	Lead Temperature (excluding dice; soldering, 10s)+300°C Soldering Temperature (reflow)
28-Pin Plastic DIP (derate 9.09mW/°C above +70°C)727mW 28-Pin Wide SO (derate 12.50mW/°C above +70°C)1000mW 28-Pin PLCC (derate 10.53mW/°C above +70°C)842mW	Plastic DIP, Wide SO, TSSOP       +260°C         PLCC       +245°C         CERDIP, Dice       +240°C

**Note 1:** Signals on S\_, D\_, A0, A1, A2, A3, or EN exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS—Dual Supplies**

(V+ = 15V, V- = -15V, V<sub>GND</sub> = 0V, V<sub>AH</sub> = +2.4V, V<sub>AL</sub> = +0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS		
SWITCH	,									
Analog Signal Range	Vanalog	(Note 3)				-15		+15	V	
Drain-Source On-Resistance	R <sub>DS</sub> (ON)	Is = -1.0mA,		T <sub>A</sub> = +25°C	,		60	100	Ω	
Dialit-Source Off-Resistance	I INDS(ON)	$V_D = \pm 10V$		TA = TMIN to	о Тмах			125	52	
On-Resistance Matching	ΔR <sub>DS(ON)</sub>	$I_S = -1.0 \text{mA},$		$T_A = +25^{\circ}C$	,		1.5	8	Ω	
Between Channels	ALIDS(ON)	$V_D = \pm 10V$ (No	ote 4)	$T_A = T_{MIN} t_0$	o T <sub>MAX</sub>			10	22	
On-Resistance Flatness	RFLAT	$I_S = -1.0 \text{mA},$		$T_A = +25^{\circ}C$	,		1.8	9	Ω	
On-nesistance mathess	INFLAT	$V_D = \pm 5V \text{ or } 0V$	V	$T_A = T_{MIN} t_0$	о Т <sub>МАХ</sub>			12	_ \(\Omega_2\)	
Source-Off Leakage Current (Note 5)		V <sub>D</sub> = +10V, V <sub>S</sub> = ±10V, V <sub>EN</sub> = 0V		T <sub>A</sub> = +25°C	,	-0.5	+0.01	+0.5		
	I <sub>S(OFF)</sub>			$T_A = T_{MIN}$	C, D	-5		+5	nA	
				to T <sub>MAX</sub>	А	-50		+50	1	
	I <sub>D</sub> (OFF)	V <sub>D</sub> = ±10V, V <sub>S</sub> = +10V, V <sub>EN</sub> = 0V	DG406	T <sub>A</sub> = +25°C	,	-1	+0.02	+1		
				$T_A = T_{MIN}$	C, D	-40		+40		
Drain-Off Leakage Current				to T <sub>MAX</sub>	А	-200		+200	nA	
(Note 5)		$V_D = +10V,$ $V_S = \pm 10V,$ $V_{EN} = 0V$	DG407	T <sub>A</sub> = +25°C	,	-1	+0.02	+1		
				$T_A = T_{MIN}$	C, D	-20		+20		
				to T <sub>MAX</sub>	А	-100		+100		
				T <sub>A</sub> = +25°C	,	-1	+0.02	+1		
		$V_D = \pm 10V$ ,	DG406	$T_A = T_{MIN}$	C, D	-40		+40		
Drain-On Leakage Current (Note 5)	ID(ON) + IS(ON)	Vs = ±10V, sequence		to T <sub>MAX</sub>	А	-200		+200	nA	
		each switch	DG407	T <sub>A</sub> = +25°C	,	-1	+0.02	+1		
				TA = TMIN	C, D	-20		+20		
				to T <sub>MAX</sub>	А	-100		+100		

# **ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)** (V+ = 15V, V- = -15V, V<sub>GND</sub> = 0V, V<sub>AH</sub> = +2.4V, V<sub>AL</sub> = +0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
INPUT	I	I						I
Input Current with Input Voltage High	I <sub>AH</sub>	V <sub>A</sub> = 2.4V or 15	5V		-1.0		+1.0	μΑ
Input Current with Input Voltage Low	I <sub>AL</sub>	VEN = 0V or 2.4 VA = 0V	1V,		-1.0		+1.0	μΑ
SUPPLY								
Power-Supply Range					±4.5		±20	V
		V <sub>EN</sub> = V <sub>A</sub> = 0V	or 5 0\/	T <sub>A</sub> = +25°C		16	30	μΑ
Positive Supply Current	l+	VEN = VA = UV	01 5.0 V	TA = TMIN to TMAX			75	μΑ
1 Ositive Supply Current	1+	VEN = 2.4V,		T <sub>A</sub> = +25°C		0.075	0.5	mA
		$V_{A(ALL)} = 0V$		$T_A = T_{MIN}$ to $T_{MAX}$			1	
Negative Supply Current	  -	$V_{EN} = 2.4V,$		T <sub>A</sub> = +25°C	-1		+1	μΑ
	'	$V_{A(ALL)} = 0V$		$T_A = T_{MIN}$ to $T_{MAX}$	-10		+10	μπ
DYNAMIC		ı						
Transition Time	ttrans	Figure 2		T <sub>A</sub> = +25°C		110	300	ns
				TA = TMIN to TMAX			400	
Break-Before-Make Interval	topen	Figure 4		T <sub>A</sub> = +25°C	10	40		ns
Enable Turn-On Time	ton(EN)	Figure 3	TA = +25°C		130	200	ns	
	- ( )		TA = TMIN to TMAX			400		
Enable Turn-Off Time	toff(EN)	Figure 3		T <sub>A</sub> = +25°C		55	150	ns
	` ′			TA = TMIN to TMAX			300	
Charge Injection (Note 3)	Q	$C_L = 1.0 nF,$ $V_S = 0V,$ $R_S = 0\Omega,$ Figure	e 5	T <sub>A</sub> = +25°C		2	15	рС
Off-Isolation (Note 6)	Viso	$V_{EN} = 0V,$ $R_L = 1k\Omega,$ $f = 100kHz, Fig$	jure 6	T <sub>A</sub> = +25°C		-69		dB
Crosstalk Between Channels	VcT	$V_{EN} = 2.4V,$ $f = 100kHz,$ $V_{GEN} = 1V_{P-P},$ $R_L = 1k\Omega, Figu$	re 7	T <sub>A</sub> = +25°C		-92		dB
Logic Input Capacitance	CIN	f = 1MHz		T <sub>A</sub> = +25°C		8		pF
Source-Off Capacitance	Cs(off)	f = 1MHz, VEN = VS = 0V, Figure 8		T <sub>A</sub> = +25°C		8		pF
Drain-Off Capacitance	C <sub>D</sub> (OFF)	f = 1MHz, VEN = 0.8V,	1 1 1 1 1 2 4 1 1 1	T <sub>A</sub> = +25°C		130		pF
Diain-Oil Capacitance	- OD(OFF)	$V_D = 0V$ , Figure 8	DG407	1A - +23 U		65		Pi
Drain-Source On	C <sub>D(ON)</sub>	f = 1MHz, V <sub>EN</sub> = 2.4V,	DG406	T <sub>A</sub> = +25°C		140		pF
Capacitance			14 - 120 0		70			

### **ELECTRICAL CHARACTERISTICS—Single Supply**

 $(V+ = 12V, V- = 0V, V_{GND} = 0V, V_{AH} = +2.4V, V_{AL} = +0.8V, T_{A} = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH	•						
Analog Signal Range	Vanalog	(Note 3)		0		12	V
Drain-Source On-Resistance	R <sub>DS(ON)</sub>	I <sub>S</sub> = -1.0mA V <sub>D</sub> = 3V or 10V	T <sub>A</sub> = +25°C		120	175	Ω
DYNAMIC							
Transition Time (Note 3)	t <sub>TRANS</sub>	V <sub>S1</sub> = 8V, V <sub>S16</sub> = 0V, V <sub>A</sub> = 0V, Figure 2	T <sub>A</sub> = +25°C		130	450	ns
Enable Turn-On Time (Note 3)	ton(EN)	V <sub>AL</sub> = 0V, V <sub>S1</sub> = 5V, Figure 3	T <sub>A</sub> = +25°C		105	600	ns
Enable Turn-Off Time (Note 3)	toff(EN)	V <sub>AL</sub> = 0V, V <sub>S1</sub> = 5V, Figure 3	T <sub>A</sub> = +25°C		80	300	ns
Charge Injection (Note 3)	Q	$C_L = 1.0$ nF, $V_{S1} = 0$ V, $R_S = 0$ \Omega	T <sub>A</sub> = +25°C		2	10	рС

**Note 2:** The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.

Note 3: Guaranteed by design.

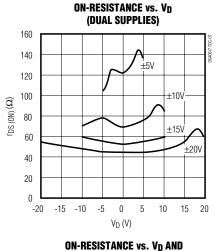
Note 4: ΔRON = RON(MAX) - RON(MIN). On-resistance match between channels and flatness are guaranteed only with specified voltages. Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured at the extremes of the specified analog signal range.

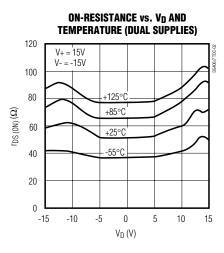
Note 5: Leakage parameters are 100% tested at the maximum-rated hot temperature and guaranteed by correlation at +25°C.

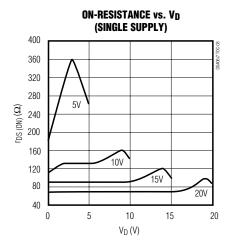
**Note 6:** Off-isolation =  $20\log V_D/V_S$ , where  $V_D$  = output and  $V_S$  = input to off switch.

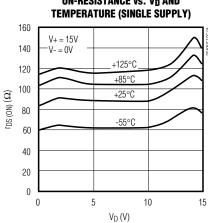
**Typical Operating Characteristics** 

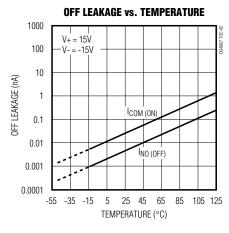
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ 

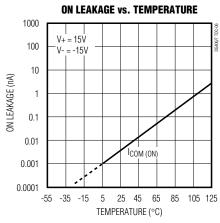


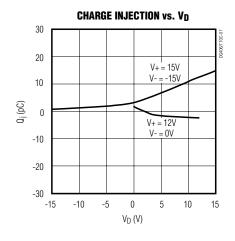


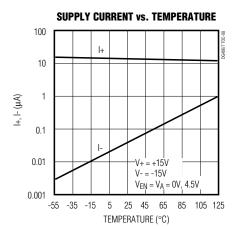












### **Pin Descriptions**

DG406 PIN	NAME	FUNCTION
1	V+	Positive Supply Voltage Input
2, 3, 13	N.C.	No Connection. Not internally connected.
4–11	S16-S9	Bidirectional Analog Inputs
12	GND	Ground
14–17	A3-A0	Address Inputs
18	EN	Enable Inputs
19–26	S1–S8	Bidirectional Analog Inputs
27	V-	Negative Supply Voltage Input
28	D	Bidirectional Output

DG407 PIN	NAME	FUNCTION
1	V+	Positive Supply Voltage Input
2	DB	Bidirectional Output B
3, 13, 14	N.C.	No Connection. Not internally connected.
4–11	S8B-S1B	Bidirectional Analog Inputs
12	GND	Ground
15, 16, 17	A2, A1, A0	Address Inputs
18	EN	Enable Input
19–26	S1A-S8A	Bidirectional Analog Inputs
27	V-	Negative Supply Voltage Input
28	DA	Bidirectional Output A

### **Applications Information**

#### Operation with Supply Voltages Other than ±15V

Using supply voltages other than ±15V reduces the analog signal range. The DG406/DG407 switches operate with ±4.5V to ±20V bipolar supplies or with a +5V to +30V single supply; connect V- to GND when operating with a single supply. Also, both device types can operate with unbalanced supplies such as +24V and -5V. The *Typical Operating Characteristics* graphs show typical on-resistance with 20V, 15V, 10V, and 5V supplies. (Switching times increase by a factor of two or more for operation at 5V.)

#### **Overvoltage Protection**

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs and analog signals. If power-supply sequencing is not possible, add two small signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog

signal range to 1V above V+ and 1V below V-, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and V- should not exceed +44V.

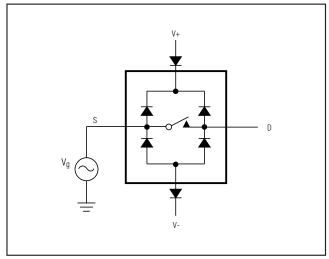


Figure 1. Overvoltage Protection Using External Blocking Diodes

## **Test Circuits/Timing Diagrams**

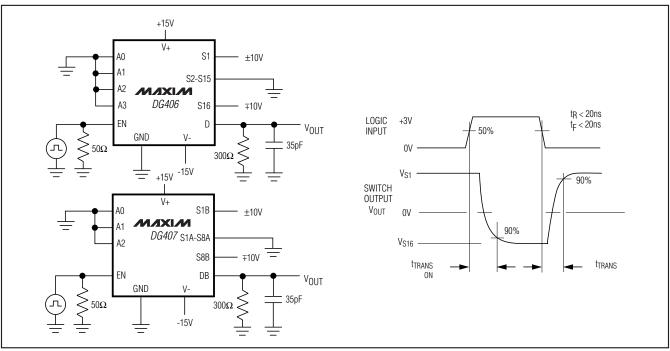


Figure 2. Transition Time

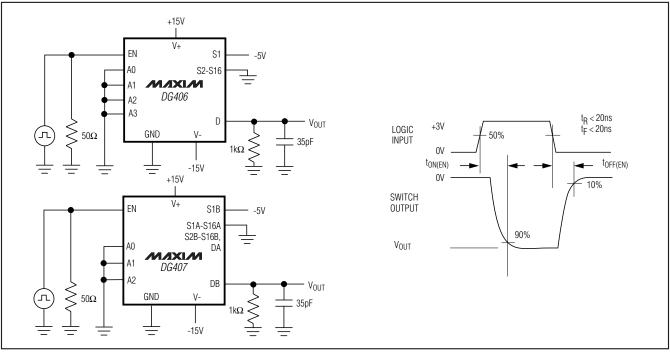


Figure 3. Enable Switching Time

## Test Circuits/Timing Diagrams (continued)

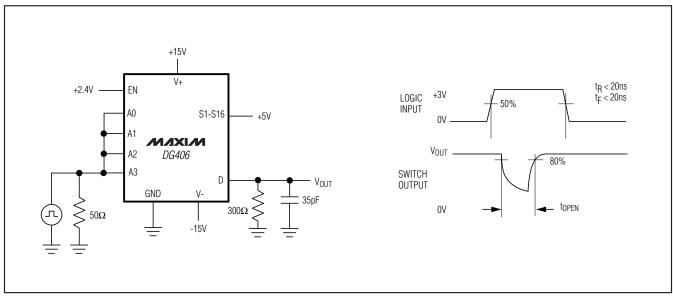


Figure 4. Break-Before-Make Interval

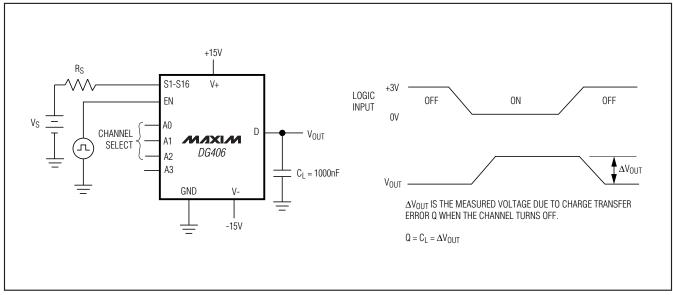


Figure 5. Charge Injection

# Test Circuits/Timing Diagrams (continued)

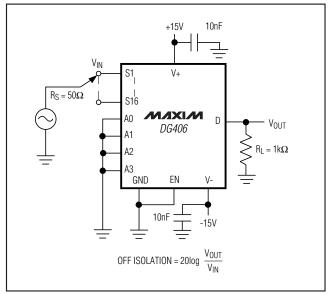


Figure 6. Off-Isolation

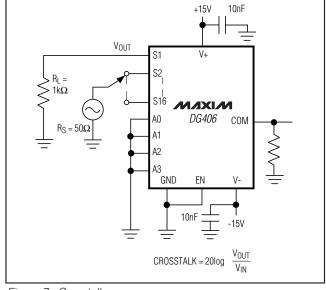


Figure 7. Crosstalk

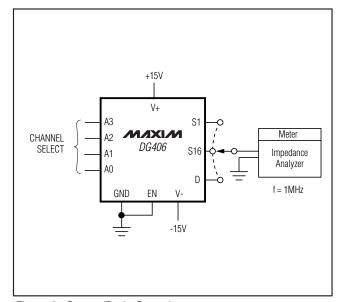
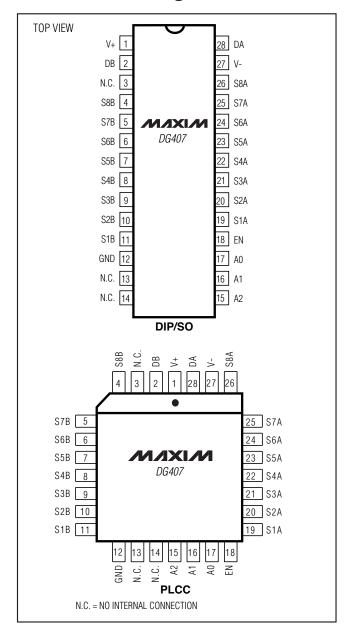
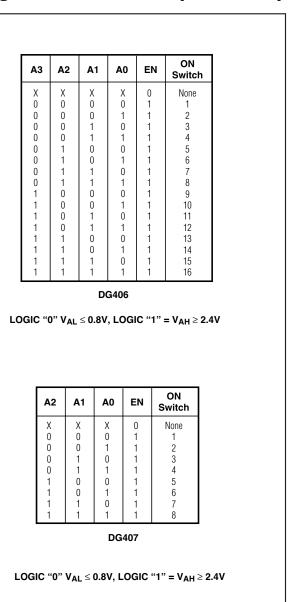


Figure 8. Source/Drain Capacitance

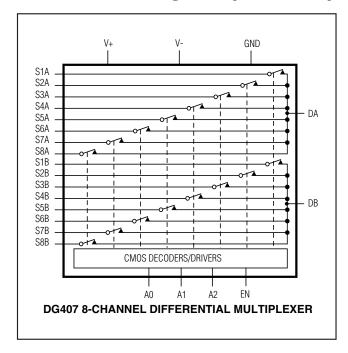
## Pin Configurations/Functional Diagrams/Truth Tables (continued)





# Improved, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

### \_Functional Diagrams (continued)



### \_Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
<b>DG407</b> CJ+	0°C to +70°C	28 Plastic DIP
DG407CWI+	0°C to +70°C	28 Wide SO
DG407C/D+	0°C to +70°C	Dice*
DG407DJ+	-40°C to +85°C	28 Plastic DIP
DG407EWI+	-40°C to +85°C	28 Wide SO
DG407DN+	-40°C to +85°C	28 PLCC
DG407AK	-55°C to +125°C	28 CERDIP
DG407EUI+	-40°C to +85°C	28 TSSOP

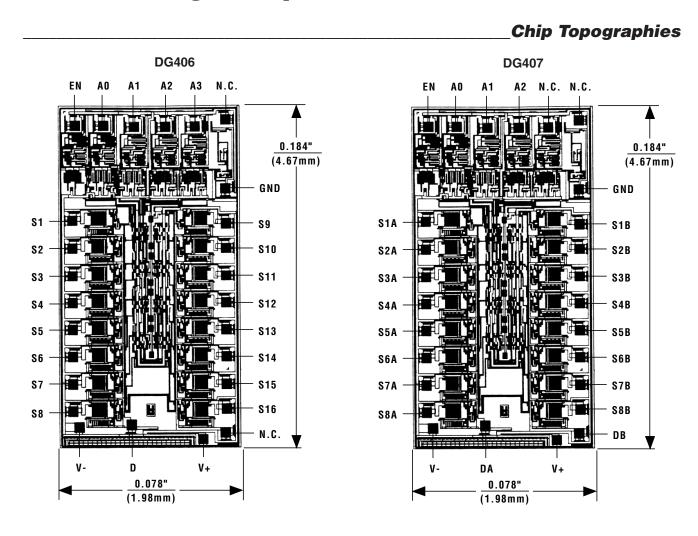
<sup>\*</sup>Contact factory for dice specifications.

### Package Information

For the latest package outline information and land patterns, go to <a href="www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
28 PDIP	P28+3	<u>21-0044</u>
28 Wide SO	W28+6	21-0042
28 PLCC	Q28+4	21-0049
28 TSSOP	U28+2	21-0066
28 CERDIP	J28+2	21-0046

<sup>+</sup>Denotes a lead(Pb)-free/RoHS-compliant package.



N.C. = NO INTERNAL CONNECTION

SUBSTRATE IS INTERNALLY CONNECTED TO V+

SUBSTRATE IS INTERNALLY CONNECTED TO V+

# Improved, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

### Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
6 3/10		Updated the minimum limit of the single supply range.	1, 6
		Added the soldering temperature of all packages to the <i>Absolute Maximum Ratings</i> .	2

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